2SK2374

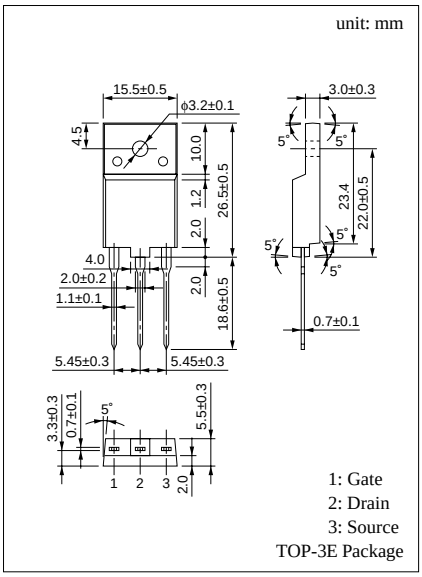
Silicon N-Channel Power F-MOS FET

■ Features

- Avalanche energy capacity guaranteed
- High-speed switching
- Low ON-resistance
- No secondary breakdown

■ Applications

- Contactless relay
- Diving circuit for a solenoid
- Driving circuit for a motor
- Control equipment
- Switching power supply



■ Absolute Maximum Ratings (T_C = 25°C)

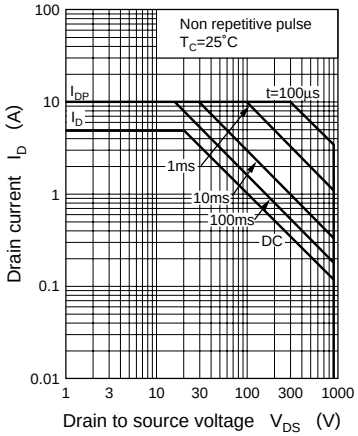
Parameter		Symbol	Ratings	Unit
Drain to Source breakdown voltage		V_{DSS}	900	V
Gate to Source voltage		V_{GSS}	±30	V
Drain current	DC	I_D	±5	A
	Pulse	I_{DP}	±10	A
Avalanche energy capacity		EAS*	45	mJ
Allowable power dissipation	T_C = 25°C	P_D	100	W
	Ta = 25°C		3	
Channel temperature		T_{ch}	150	°C
Storage temperature		T_{stg}	–55 to +150	°C

* L = 3.6mH, I_L = 5A, 1 pulse

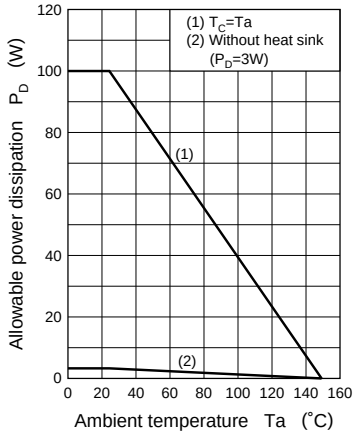
■ Electrical Characteristics (T_C = 25°C)

Parameter	Symbol	Conditions	min	typ	max	Unit
Drain to Source cut-off current	I_{DSS}	V_{DS} = 720V, V_{GS} = 0			100	µA
Gate to Source leakage current	I_{GSS}	V_{GS} = ±30V, V_{DS} = 0			±1	µA
Drain to Source breakdown voltage	V_{DSS}	I_D = 1mA, V_{GS} = 0	900			V
Gate threshold voltage	V_{th}	V_{DS} = 25V, I_D = 1mA	2		5	V
Drain to Source ON-resistance	$R_{DS(on)}$	V_{GS} = 10V, I_D = 3A		2	2.8	Ω
Forward transfer admittance	$\|Y_{fs}\|$	V_{DS} = 25V, I_D = 3A	1.5	3.5		S
Diode forward voltage	V_{DSF}	I_{DR} = 5A, V_{GS} = 0			–1.6	V
Input capacitance (Common Source)	C_{iss}	V_{DS} = 20V, V_{GS} = 0, f = 1MHz		1400		pF
Output capacitance (Common Source)	C_{oss}			140		pF
Reverse transfer capacitance (Common Source)	C_{rss}			60		pF
Turn-on time (delay time)	$t_{d(on)}$	V_{DD} = 200V, I_D = 3A, V_{GS} = 10V, R_L = 66.6Ω		30		ns
Rise time	t_r			60		ns
Fall time	t_f			60		ns
Turn-off time (delay time)	$t_{d(off)}$			170		ns
Thermal resistance between channel and case	$R_{th(ch-c)}$				1.25	°C/W
Thermal resistance between channel and atmosphere	$R_{th(ch-a)}$				41.67	°C/W

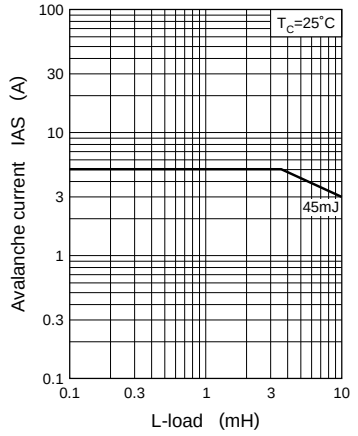
Area of safe operation (ASO)



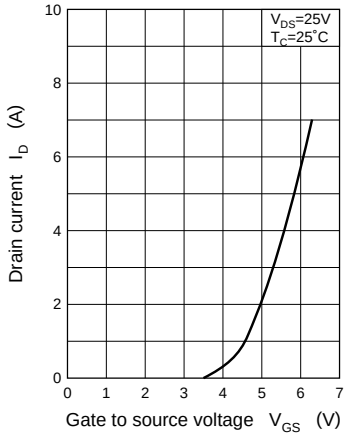
P_D — Ta



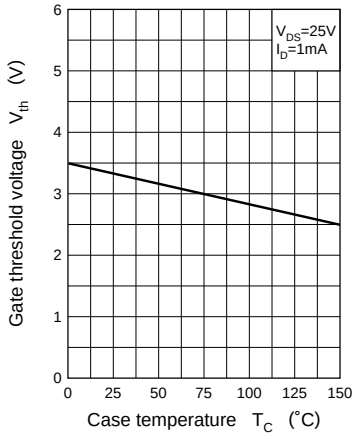
IAS — L-load



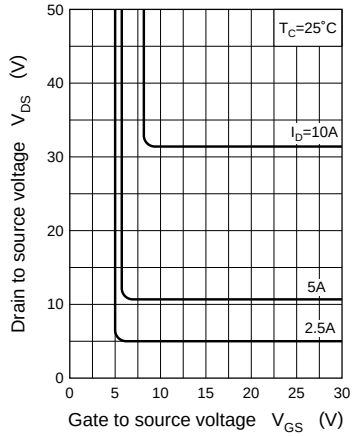
I_D — V_{GS}



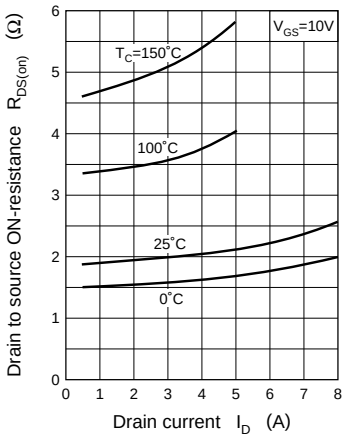
V_{th} — T_C



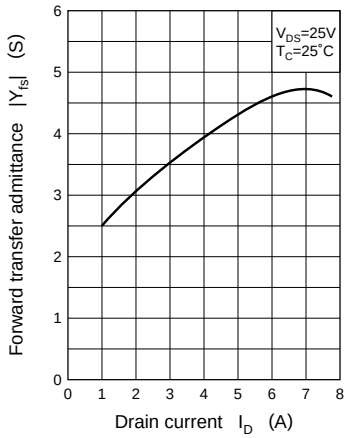
V_{DS} — V_{GS}



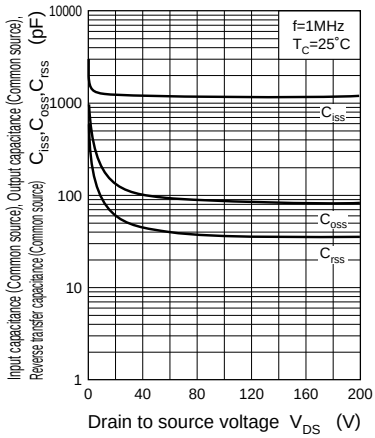
$R_{DS(on)}$ — I_D



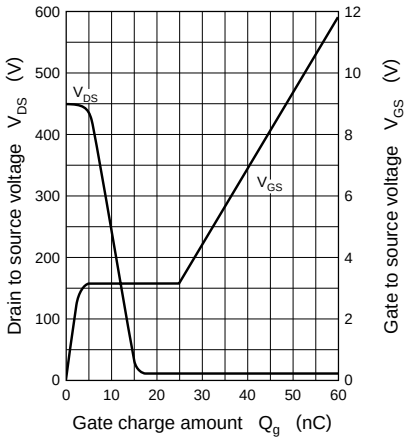
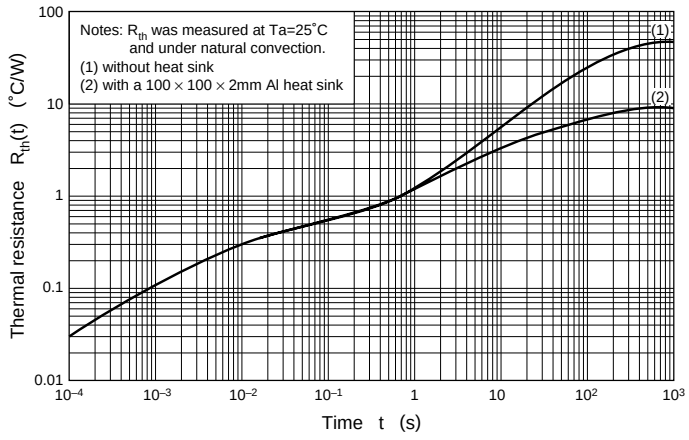
$|Y_{fs}|$ — I_D



C_{iss}, C_{oss}, C_{rss} — V_{DS}



V_{DS}, V_{GS} — Q_g



$R_{th(t)}$ — t